

REMARKS

The Office Action has required restriction, under 35 U.S.C. §121, to either claims 1-6 and 17-20 (Group I), drawn to a memory device and a method for forming a memory device, or claims 7-16 (Group II), drawn to a method of doping fins of a semiconductor device. The Office Action asserts that these inventions are related as process of making and product made. In view of the restriction requirement, Applicants elect claims 1-6 and 17-20 of Group I, drawn to a memory device and a method for forming a memory device, without traverse.

In view of the foregoing remarks, Applicants respectfully request the Examiner's reconsideration of this application, and the timely allowance of the elected claims. To the extent necessary, a petition for an extension of time under 37 CFR § 1.136 is hereby made. Please charge any shortage in fees due in connection with the filing of this paper, including extension of time fees, to Deposit Account No. 50-1070 and please credit any excess fees to such deposit account.

Respectfully submitted,

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